M an ipulating the super uid -M ott insulator transition of a Bose -E instein condensate in an amplitude -m odulated optical lattice.

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Abstract

The super uid -M ott insulator transition in a BEC con ned in an amplitude -m odulated optical lattice can be manipulated by the modulation strength. Two standing laser waves of main and sideband frequencies of an optical lattice induce a R am an transition; due to resonant R am an driving the critical value of the transition parameter depends on the modulation strength and the detuning from resonance and can be tuned to a given value. It is shown that there is an interval of the initial M Iphase, in which a modulation sw itches the M I phase to the SF phase.

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Manipulating a phase transition is a subject of great interest to physicists. A physical system that crosses the boundary between two phases changes its properties in a fundam ental way. Second - order phase transitions usually term ed classical phase transitions, take place at a nite tem perature, and they are accomplished by changing the tem perature. A quantum phase transition is one that occurs at absolute zero of tem perature. The quantum phase transitions have attracted much interest in recent years. These transitions are accom plished by changing not the tem perature, but som e parameter in the Ham iltonian of the system. This parameter is the lattice laser intensity for a Bose - Einstein condensate (BEC) in an optical lattice, which controls the super uid -M ott insulator transition; the charging energy in Josephson - junction arrays. which controls the superconductor - insulator transition; the magnetic eld in a quantum - Hall system, which controls the transition between the Hallplateaus; disorder in a conductor near its metal - insulator transition. The com petition between two interactions is fundam ental to quantum phase transitions and inherently di erent from classical phase transitions which are driven by the competition between inner energy and entropy. The quantum phase transition are driven by the interplay of the di erent contributions to the Ham iltonian of the system. For instance, for a BEC in an optical lattice the two terms in the Ham iltonian represent the self - interaction of the atoms in the lattice site and the hopping of the atom s between the sites, for Josephson - junction arrays they represent the charging energy of each grain and the Josephson coupling energy between grains; the competition between them determ ines the quantum phase transition.

The experimental observation of Bose-E instein condensation in a dilute gas of ultracold trapped atoms [1-3] has generated much interest in manipulating such coherent matter by external electromagnetic elds. Recently atoms have been conned in optical potentials created by standing light waves [4, 5], with the wavelength of the optical potential much smaller than the dimensions of the trap. The unique prospects of this new class of system (the correlated bosons on a lattice [6-9]) became evident. A transition to a M ott insulator becomes possible when a super uid like a BEC is placed in a periodic potential. This quantum phase transition is characterized by the competition between two interactions: the

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tendency of the particles to hop into adjacted wells (kinetic energy), and the interparticle forces that keep them in separate wells (potential energy). A sthe strength of the interaction term (the repulsive interaction energy U between two atom s) relative to the tunneling term (the tunneling J between adjacent sites in the Bose – Hubbard Hamiltonian) is changed, the system reaches a quantum critical point in the ratio of U=J, for which the system will undergo a quantum phase transition from the super uid state (SF) to the M ott insulator state (M I). A sem inal experiment by G reiner and collaborators [5] dem onstrated a quantum phase transition in a Bose – E instein condensate from a super uid state into a M ott insulator state, by varying the lattice laser intensity as proposed theoretically in [10].

The balance between two interactions, which determ ines a quantum phase transition can be changed by a time - dependent action, and thereby a quantum phase transition can be manipulated. In this letter, we propose this basic idea which will be used for the SF -M I transition in a BEC and for the external Josephson e ect between two BEC's.

We consider a manipulation of the SF -M I transition in a BEC in an amplitude -m odulated optical lattice. The such optical lattice can be created by interfering pair of amplitude -m odulated beam s. In general, there are the two generic types of the manipulation. The e ect of the modulation is to modulate the optical lattice potential so that it becomes a time - dependent optical lattice potential which the depth of the potential well is

$$V_{0}(t) = V_{0}(1 + "\cos!_{M} t); " < 1;$$
(1)

where " is the modulation strength, $!_{M}$ is the modulation frequency. If the period of modulation $2 = !_{M}$ is larger the nonequilibrium dynamic time _{noneq}, then the time behavior of a BEC in an amplitude -modulated optical lattice is quasistatic. The nonequilibrium dynamic time _{noneq} for trapped bosonic atom s in an optical lattice potential was considered in Ref.[11] and was shown that the characteristic time of the dynam ical restoration of the phase coherence in the dom ain of a quantum phase transition is the integer of the order of 10 multiplied by a Josephson time h=J. One is a resonant mechanism which operates when the modulation frequency $!_{M}$ is close to the excited internal state of a BEC. A resonant

mechanism is determined by change in the population due to a resonant driving. In a BEC in a periodic potential the characteristic energetic scale of the band structure [12,13] is the recoil energy E_R . And, usually, E_R exceeds J, and the quasistatic behavior is not valid. However, in this case is more convenient to use a picture that an amplitude -m odulated eld can be presented as a set of m onochrom atic elds (m ain on frequency ! and sideband on frequencies ! $!_{M}$). These elds can induce a Ram an transition between the two internal states of a BEC ja > and jb > . A resonant eld via a two - photon (Raman) transition changes the population of the ground state of a BEC. Therefore, the on - site interaction and the tunneling, which depend on the population, are also changed. However, due to this changing population the variations of the on -site interaction and the tunneling are di erent; therefore, the balance between kinetic and potential energies, which determines a phase transition, is changed. As a result, we have a modi cation of the quantum phase transition. The modi cated by a resonant modulation ratio $U_r=J_r$ is less than this ratio without a m odulation. The phase transition [6,9,14] occurs at U=J=z 5:8= const, with z being the num ber of next neighbours of a lattice site. The system has the renorm alized by a modulation parameters Ur and Jr of a Bose - Hubbard Hamiltonian and reaches a quantum critical point if $U_r = J_r = const w$ ith the same constant, then it means that the optical potential critical depth in an amplitude -m odulated resonant lattice V_{0res}^{cr} increases, because the ratio of U=J is the growing function [10, 14] on the optical potential depth. Second is a nonresonant mechanism for which we will use a direct time - dependent description. A nonresonant mechanism of manipulation is in operation for a quasistatic regime $!_{M} < 2 \frac{1}{noneg}$, therefore, if V_0 corresponds to a quantum critical point $V_0^{\,\mathrm{cr}}$ then as the time runs, the system goes from a super uid to an insulator and back again with frequency $!_{M}$. The ratio of U=J is a nonlinear function on the laser intensity with the leading exponential dependence on the strength of the periodic potential V_0 . If we have a time - dependent lattice laser intensity, then, although $\overline{V_0(t)} = V_0$, due to the nonlinearity a time - averaged ratio of $\overline{U=J}$ will be dierent from a ratio of U=J without a modulation. For a small " we have the time - averaged U=J = U=J + (U=J), where the bar stands for a time average and (U=J)

is proportional to the time - averaged $"^2 \overline{\cos^2}!_M t$ (the time - averaged of the modulation harm onic oscillation to the lowest even order power).

A Bose - Einstein condensate in an amplitude - modulate optical lattice.

In resonant case the system is excited by an o -resonant R am an (two -photon) driving with the Rabi frequency $_{\rm R}$. In an amplitude -modulated optical lattice two standing laser waves of frequencies ! and ! $!_{M}$ (! M !) drive an atom in a R am an scheme. The e ective two-photon Rabi frequency is given in term sof the single-photon Rabi frequencies and ⁰ of the elds on the main ! and sideband ! ⁰ = ! !_M frequencies as $_{R} = \frac{}{2}^{0}$. For the amplitude - modulated laser beams with the modulation strength "we have for standing waves $_{R}(x) = \frac{\sqrt{2}}{2} = \frac{\sqrt{2}}{h}$, here is the far-detuning of the laser beam s from the atom ic resonance (the closest neighboring optical dipole transition), and $V_0(x) = \int_{j=1}^{P} V_{j0} \cos^2 kx_j$ is the optical lattice potential with wave vectors $k = \frac{2}{2}$ and the wavelength of the laser beam s on the main frequency, and we are om itted the term s proportional to the sm all param eter k $x = \frac{!_{M}}{c}x$ 1, where k k^{0} k, for x < 10^{4} cm; $!_{M}$ 10^{7} s¹, this parameter is about 10⁷. The eigenstates of a BEC are Bloch wave functions, and an appropriate superposition of B loch states yields a set of W annier functions which are localized on the individual lattice sites. We will consider as the two distinct internal states a and b coupled via a two -photon (Raman) transition the two di erent vibrational states in the W annier basis, where the initial state a is the lowest vibrational state of the harm onic oscillator with n = 0 and the state b is the excited vibrational state with $n \in 0$. The equations of m otion of a strongly (the Rabiregine) driven [15,16] BEG resemble the Bloch equations describing a driven two-level system if the external driving eld h R is much larger than the di erence in the two -body interaction K (this energy [17] is proportional to $U_a + U_b = 2U_{ab}$). We consider a steady state driving regime, in which the solution ' (x) of the Bloch equation of the standard Rabiproblem is determined on the parameters of the eld (the Rabifrequency and the detuning from resonance = $!_{M}$ ($!_{b}$ $!_{a}$). Therefore, the boson eld operator for atom (x) can be represent by an expansion in the W annier basis, which is a sum over

the lattice i, and multiplied by the function '(x), which is determined by the Raman eld, a (x) = $\frac{P}{i}a_iw_0(x - x_i)'(x)$, where the operators a_i are the operators on lattice site i. In order to avoid a su cient population of the excited state b, we are assume R < r, then $r^2(x)' = 1 - \frac{1}{2}(-\frac{R}{2}(x))^2$. In the tight -binding lim it the W annier states are localized and can be approximated [10,14] by the harmonic oscillator wave function $w_n(x - x_i)$ of number n. The size of the ground - state oscillator wave function in a lattice is much less than the lattice period =2; ; where the size $= -\frac{q}{2m} - \frac{h}{2m}$ determined by the atom ic m ass m and the oscillation frequency in the wells (see, for example [10]) $_j = -\frac{q}{4E_RV_{j0}} = h$, then the inequality $h_R - K$ reduces to the following $V_0 - K$. This inequality can be easily fulled, because, usually, K = h - 1 - 0 (1s⁻¹ for a blue detuning [19] = 514nm for sodium. We not for $(\frac{vv_0}{h})^2 - 1$ that the parameters of a Bose - Hubbard Ham iltonian m odi cated by a resonant m odulation are

$$J_r ' J [1 + \frac{3}{2} (\frac{"V_0}{h})^2]; U_r ' U [1 (\frac{"V_0}{h})^2]:$$
 (2)

The parameters of a Bose – Hubbard Ham iltonian J and U depend on the optical lattice depth V_0 , and they were calculated analytically in Ref.[14] in the tight – binding lim it in terms of the m icroscopic parameters of the atoms in the optical lattice. We nd that for a resonant amplitude – m odulated optical lattice the ratio $U_r=J_r$ is always less than without a modulation, then it means that for a resonant modulation the optical potential critical depth V_0^{cr} increases. The corresponding tuning V_0^{res} (") of the optical lattice critical depth is determined for $V_0 = E_R$ by

$$V_{0}^{\text{res}}(") = \frac{V_{0}^{\text{cr}}(")}{V_{0}^{\text{cr}}} \frac{V_{0}^{\text{cr}}}{V_{0}^{\text{cr}}} - \frac{5}{2} \left(\frac{"V_{0}^{\text{cr}}}{h}\right)^{2} \left(\frac{E_{R}}{V_{0}^{\text{cr}}}\right)^{1=2};$$
(3)

As a result, we can manipulate the super uid -M ott insulator transition of a BEC in an amplitude -m odulated optical lattice. The tuning of the optical lattice critical depth is determined by the modulation strength ". By varying the parameter "= , we can tune the critical value to a given value. Therefore, in the interval of the laser intensity V₀, for which $V_0^{cr} < V_0 < V_{0res}^{cr}$ ("), we can switch one phase to another by a modulation, and in this interval of the initial M I phase a modulation switches the M I phase to the SF phase.

For a nonresonant manipulation we will use a time – dependent potential (Eq.(1)), and there could be a modulation frequency $!_{M}$ low enough for quasistatic time behavior. Therefore, it modulates the on-site two-body interaction U and the hopping matrix element J, so that these quantities become time – dependent U (t); J (t). Note that such potential is created by interfering pair of amplitude – modulated laser beam s with the modulation strength "=2 of the electric eld amplitude, and was om itted the quadratic term for the small parameter "²=4. U sing the analytical dependencies [14, 20], we have for a time – dependent optical lattice depth

$$U(t) = \frac{p}{2} \left(\frac{g}{h}\right) \left(\frac{V_0(t)}{E_R}\right)^{1=4}; J(t) = \frac{4}{p-E_R} \left(\frac{V_0(t)}{E_R}\right)^{3=4} \exp\left[-2\frac{V_0(t)}{E_R}\right]^{1=2}:$$
(4)

Calculating the time - average of the product of U (t) by (J(t))¹ by expanding in a series about the small parameter " $\frac{2 V_0}{E_R} < 1$, we nd

$$\frac{\left(\frac{U}{J}\right)_{nr}}{\left(\frac{U}{J}\right)} \cdot \frac{\Psi^2}{4} \left[\frac{V_0}{E_R} - \frac{V_0}{E_R}\right]^{1=2} - \frac{1}{2}]; \tag{5}$$

where $g = 2h! a_s;!$ is the con ning frequency, a_s is the s-wave scattering length between two atom s, $(\frac{\overline{U}}{J})_{nr}$ is the time – average of the ratio $\frac{\overline{U}}{J}$ for a nonresonant modulation, and were on itted the small term s proportional to $({}^{n_2}\frac{V_0}{E_R})^n$ for n > 1. If ${}^{n_2}\frac{V_0}{E_R}$ is not small, then we may expand the expression for the time – dependent J (t) using Bessel functions $I_n(x)$ and the functions $\cos^n !_M$ t. In this case instead the parameter $\frac{n^2}{4} \left(\frac{V_0^{cr}}{E_R} - \frac{V_0^{cr}}{E_R} \right)^{1-2} = \frac{1}{2} \right]$ we have $I_2({}^{n_1} \frac{V_0^{cr}}{E_R})$, because, usually, $V_0=E_R$ = 10 and for n < 0.4 among $I_n(x < 1.3)$ the largest is $I_2(x)$.

An external Josephson e ect between two BECs.

Here we consider brie y the manipulation by an amplitude -m odulated laser beam an external Josephson e ect between two BECs, the full presentation will be given elsewhere.

This system is a prototype system of an array of Josephson junctions. In such systems, a superconducting - insulator phase transition is driven by the competition between the

Josephson coupling energy E ;, which govern the tunneling through the intraw ellbarriers, and the on - site interparticle interaction energy E_c . A Josephson e ect between two spatially separate BECs can be realized only with small barriers. A key element of this e ect is the Josephson coupling energy E . Based on a tunneling Ham iltonian description the dom inant Josephson term of rst order in the tunneling is proportional to the barrier transmission amplitude. Such approximation by a tunneling or transfer Hamiltonian is valid for high and narrow barriers, for which the barrier transm ission amplitude $t_{\rm ir}$ is proportional to)= h^2 ; = (_a _b)=2 is the average chem ical potential, exp(kd), where k = $\frac{1}{2m} (V_B)$ where the two BECs (a and b) con ned in a cubic volume $L^{\,3}$ are separated by a square potential barrier of height V_B and width d. A Josephson geom etry for BECsm ay be created by splitting a single condensate in a long trap into two separate parts by a narrow light sheet. produced by a strongly detuned laser beam . Because the repulsive potential due to the ac Stark shift is proportional to the laser power, thus the height of the barrier is determ ined by the laser intensity. Therefore, if we create the necessary for a Josephson e ect two -well potential by an amplitude -m odulated laser beam, then the potential barrier height V_B will be an amplitude -m odulated tim e -dependent one (sim ilarly Eq.(1)). Just as the analytical dependencies of the tunneling J between ad jacent sites of a BEC in an am plitude -m odulated optical lattice and the transm ission amplitude t_{lr} are sim ilar, so the time - average of this barrier transmission amplitude \overline{t}_{lr} is dier from the value t_{lr} without a modulation. As a result, the Josephson coupling energy E i, which is proportional to the barrier transmission am plitude, is also can be manipulated by the abovem entioned manner.

In sum m ary, the super uid -M ott insulator transition in a BEC in an optical lattice can be m anipulated by an amplitude -m odulated m anner. This manipulating is caused by the change of the balance two interactions, which determ ines a quantum phase transition, by a time-dependent action. There are two mechanisms of the manipulation. One, resonant mechanism is in operation for the modulation frequency closed to the excited internal state of a BEC, and two standing laser waves of main and sideband frequencies of an amplitude -m odulated optical lattice induce a R am an transition. Due to resonant R am an driving the population of the ground state of a BEC changes. Therefore, the on - site interaction and the atom ic tunneling are also changed, and their ratio is di erent from the ratio without a resonant m odulation. As a result, the optical lattice critical depth is other than without a m odulation, this tuning is determ ined by the square of the m odulation strength. The optical lattice critical depth with a resonant m odulation is higher than without a m odulation, and, therefore, there is an interval of the initial M I phase, in which a m odulation switches the M I phase to the SF phase. Second, nonresonant m echanism is determined by the nonlinear dependence of the ratio of the repulsive interaction to the tunneling on the optical lattice depth. D ue to this nonlinearity for the harm onic m odulation of the optical lattice depth the tim e - averaged ratio is di erent from the ratio without a m odulation. The proposed m echanism of m anipulating and controlling Bose - E instein condensates m akes it possible to tune the critical value of param eter of the quantum phase transition to a given value.

In conclusion, tuning and conducting, in general, the super uid -M ott insulator transition in a BEC in an optical lattice by a time – dependent action (in particular, in an amplitude – modulated optical lattice) can be a path to the solution of the general problem of controlling a quantum phase transition.

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REFERENCES

- [1] M.H.Anderson et al, Science 269, 198 (1995).
- [2] C.C.Bradley et al, Phys. Rev. Lett. 75, 1687 (1995).
- [3] K.B.Davis et al, Phys. Rev. Lett. 75, 3969 (1995).
- [4] C.Orzelet al, Science 291, 2386 (2001).
- [5] M.Greiner et al, Nature (London) 415, 39 (2002).
- [6] M.P.A.Fisher et al, Phys. Rev. B 40, 546 (1989).
- [7] W.Krauth and N.Triverdi, Europhys. Lett. 14, 627 (1991).
- [8] M. Cha et al, Phys. Rev. B 44, 6883 (1991).
- [9] K. Sheshadriet al, Europhys. Lett. 22, 257 (1993).
- [10] D. Jaksch et al, Phys. Rev. Lett. 81, 3108 (1998).
- [11] A.Polkovnikov, S.Sachdev, and S.M.Girvin, Phys. Rev. A 66, 053607 (2001).
- [12] K.Berg S rensen and K.M lm er, Phys. Rev. A 58, 1480 (1998).
- [13] D.D iakonov et al, Phys. Rev. A 66, 013604 (2002).
- [14] D. van Oosten, P. van der Straten, and H. T. C. Stoof, Phys. Rev. A 63, 053601 (2001).
- [15] J.W illiam set al, Phys. Rev. A 59, R31 (1999).
- [16] G.M.Genkin, Phys. Rev. A 63, 025602 (2001).
- [17] A.J.Legett, Rev.M od.Phys. 73, 307 (2001).
- [18] S.Kohler and F.Sols, Phys. Rev. Lett. 89, 060403 (2002).
- [19] D.M. Stam per-Kum et al., Phys. Rev. Lett. 80, 2027 (1998).
- [20] H.P.Buchler et al, Phys. Rev. Lett. 90, 130401 (2003).